



Bipolar NPN Bare Die – BTN069

Part Description

The BTN069 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Driver applications. PNP Complement is BTP069.

Key Parameters:

- VCBO = 400V
- VCEO = 400V
- VEBO = 6V
- hFE = 80-300 @ VCE = 10V, IC = 0.01A
- VCE(Sat) = 0.75V @ IC = 0.05A, IB = 5mA
- fT = 50 MHz @ VCE = 10V, IE = 0A
- COBO = 2pF @ VCB = 20V

Features

Designed to provide performance equivalent to MPSA44

Die Size (Unawn)

850µm X 850µm, 33 Mils X 33 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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